

SANYO Semiconductors DATA SHEET



N-Channel Silicon MOSFET MCH3431 — General-Purpose Switching Device **Applications**

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 2.5V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	۱ _D		3.5	A
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	14	A
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	1	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1.8A	2.8	4.8		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=1.8A, VGS=4V		55	72	mΩ
	RDS(on)2	ID=1A, VGS=2.5V		70	98	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		415		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		60		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		55		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		11		ns
Rise Time	tr	See specified Test Circuit.		65		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		54		ns
Fall Time	tf	See specified Test Circuit.		61		ns

Marking : ZG

Continued on next page.

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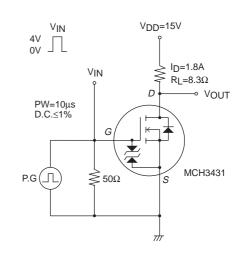
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Total Gate Charge	Qg	VDS=10V, VGS=4V, ID=3.5A		5.1		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4V, I _D =3.5A		0.95		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=10V, VGS=4V, ID=3.5A		1.4		nC
Diode Forward Voltage	VSD	IS=3.5A, VGS=0		0.87	1.2	V

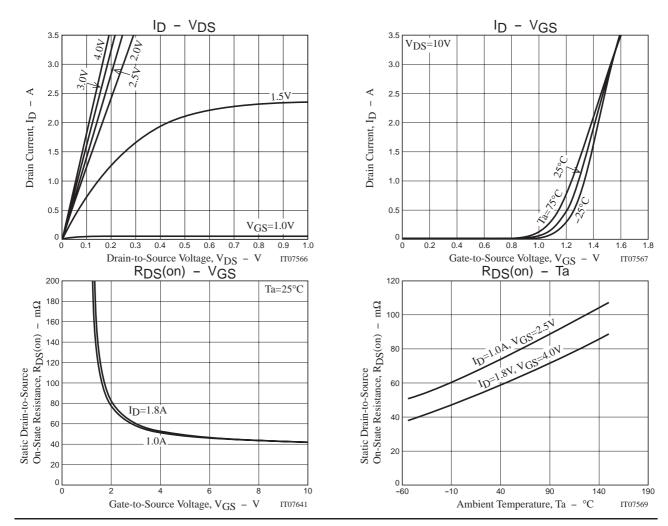
Package Dimensions

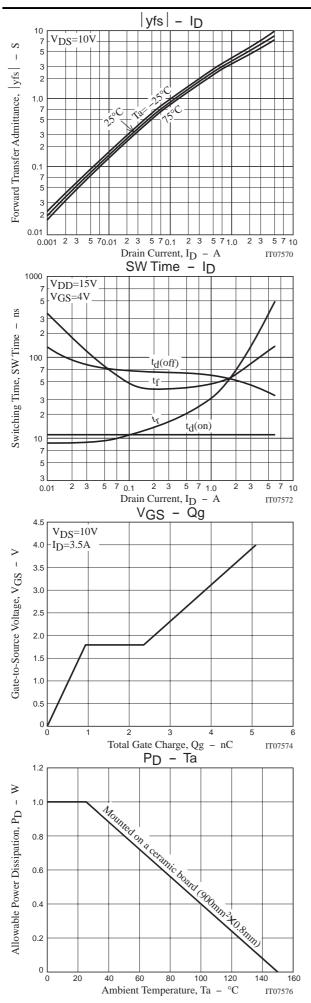
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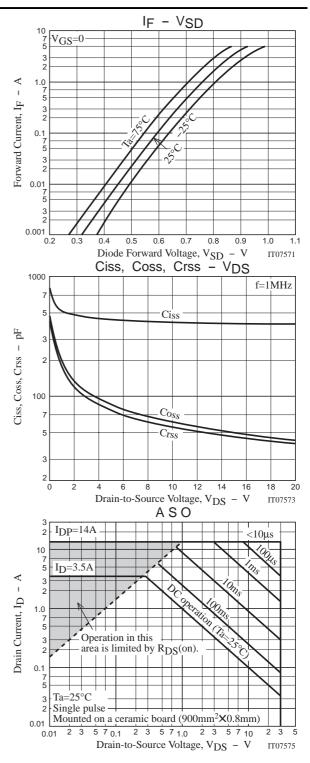
0.3 0.25 0.15 1.6 2.1 2 0.07 0.25 0.65 2.0 (Bottom view) 1 : Gate 2 : Source 0.85 3 : Drain (Top view) SANYO : MCPH3

Switching Time Test Circuit









Note on usage : Since the MCH3431 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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